

**ELECTRICAL CONDUCTIVITY OF SYNTHESIZED ZIRCON  
CERAMICS DOPED WITH DIFFERENT DOPANTS**

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# ELECTRICAL CONDUCTIVITY OF SYNTHESIZED ZIRCON CERAMICS DOPED WITH DIFFERENT DOPANTS

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The electrical conductivity enhancement of laboratory synthesized zircon ceramics, doped with different dopants has been studied using complex impedance spectroscopy. The cation dopants used in this study were  $Y^{3+}$ ,  $Fe^{3+}$ ,  $Yb^{3+}$ ,  $Mg^{2+}$ ,  $Ca^{2+}$ ,  $Na^+$ ,  $Er^{3+}$ ,  $Na^+ + Y^{3+}$  and  $Na^+ + Fe^{3+}$ . It is expected, that the presence of defects in the zircon host structure introduced by doping can lead to higher electrical conduction.

First, X-Ray Diffraction (XRD) analysis was performed on the zircon samples doped with different cations to find out whether zircon formation was successful. Then, the complex impedance measurements were performed as a function of temperature.

The XRD analysis shows that, the formation of zircon was successful in the samples doped with 10 mol %  $Y_2O_3$ , 10 mol %  $Fe_2O_3$ , 10 mol %  $Yb_2O_3$ , 10 mol %  $MgO$ , 10 mol %  $CaO$  and 10 mol %  $Er_2O_3$ . The electrical conductivity of synthesized zircon ceramics increased with increasing temperature irrespective of the dopant. A good conductivity enhancement was obtained in zircon doped with 10 mol %  $Y_2O_3$  and 10 mol %  $Fe_2O_3$  which were  $2.47 \times 10^{-5} \text{ S cm}^{-1}$  and  $1.33 \times 10^{-5} \text{ S cm}^{-1}$  at  $700^\circ \text{C}$  respectively. These values are nearly equal to the data reported in literature for natural zircon.

The conductivity enhancement in zircon samples doped with  $Y_2O_3$  and  $Fe_2O_3$  is most probably due to the motion of  $O^{2-}$  ions by vacancy mechanism. The  $O^{2-}$  ion vacancies were created as a consequence of the substitution of  $Y^{3+}$  and  $Fe^{3+}$  for  $Zr^{4+}$  or  $Si^{4+}$ . For substitution to take place the ions must be comparable in size. This indicates that, the ionic radii of  $Y^{3+}$  and  $Fe^{3+}$  are comparable to that of  $Zr^{4+}$  or  $Si^{4+}$ . However, the zircon samples doped with  $Yb_2O_3$ ,  $MgO$ ,  $CaO$  and  $Er_2O_3$  did not show any significant conductivity enhancement. This may be due to non-incorporation of these dopants into the host structure of zircon to give a defect structure as a result of the difference in ionic radii of the cations. Hence,  $O^{2-}$  vacancies were not created and the conductivity was not increased.